

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Manfred Ruehrig et al.
Serial No.: Unknown
(Priority Application No. DE 102 14 159.2)
(International Application No. PCT/DE03/00775)
Filed: Herewith
(Priority Date: March 28, 2002)
(International Filing Date: March 11, 2003)
Docket No.: I433.125.101/13.305
Title: MRAM MEMORY CELL WITH A REFERENCE LAYER AND METHOD
FOR FABRICATING (As Amended)

PRELIMINARY AMENDMENT

Mail Stop PCT
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

This Preliminary Amendment amends the Utility Patent Application filed herewith and should be used to calculate filing fees due. Prior to examination of the above-identified patent application, please amend as follows:

Preliminary Amendment

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Title: MRAM MEMORY CELL WITH A REFERENCE LAYER AND METHOD FOR FABRICATING (As Amended)

IN THE TITLE

Please replace the title with the following rewritten title:

METHOD FOR FABRICATING A REFERENCE LAYER AND MRAM
MEMORY CELL PROVIDED WITH A REFERENCE LAYER OF THIS TYPE AND
METHOD FOR FABRICATING